N-Channel 30-V (D-S) MOSFET

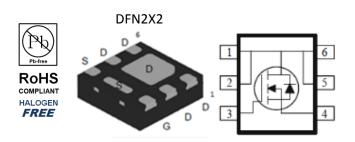
Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- Fast switching speed

Typical Applications:

- DC/DC Conversion
- Power Routing
- Motor Drives

PRODUCT SUMMARY			
Vds (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)	
30	10.5 @ V _{GS} = 10V	14	
30	18 @ V _{GS} = 4.5V	11	



ABSOLUTE MAXIMUM RATINGS (T _A = 25° C UN	ILESS OTHE	RWISE NO	TED)		
Parameter		Symbol	Limit	Units	
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage			±20	V	
Continuous Drain Current ^a	T _A =25°C	I _D	14		
Continuous Drain Current	T _A =70°C		11	А	
Pulsed Drain Current ^b		I _{DM}	50		
Continuous Source Current (Diode Conduction) ^a		۱ _s	3.8	А	
Power Dissinction ^a	T _A =25°C	P _D	3	W	
Power Dissipation ^a	T _A =70°C	U 'D	1.9	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C	

THERMAL RESIS	TANCE RATINGS				
Parameter			Maximum	Units	
Maximum Junction-to-Ambient ^a	t <= 10 sec	R _{eja}	40	°C/W	
	Steady State	ιν _θ ja	90	C/VV	

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \text{ uA}$	1			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			±100	nA	
ero Gate Voltage Drain Current	1	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
	IDSS	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25	uA	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 10 V$	20			А	
Drain-Source On-Resistance ^a	r	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 11 \text{ A}$			10.5		
	r _{DS(on)}	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 8.8 \text{ A}$			18	mΩ	
Forward Transconductance ^a	g _{fs}	V _{DS} = 15 V, I _D = 11 A		13		S	
Diode Forward Voltage ^a	V _{SD}	I _S = 1.9 A, V _{GS} = 0 V		0.77		V	
		Dynamic ^b					
Total Gate Charge	Qg	V _{DS} = 15 V, V _{GS} = 4.5 V,		11			
Gate-Source Charge	Q_gs	$v_{DS} = 15 v, v_{GS} = 4.5 v,$ $I_{D} = 11 A$		4.9		nC	
Gate-Drain Charge	Q_gd			3.5			
Turn-On Delay Time	t _{d(on)}	V _{DS} = 15 V, R _L = 1.4 Ω,		6			
Rise Time	t _r	$V_{DS} = 13 V, R_{L} = 1.4 \Omega_{2},$ $I_{D} = 11 A,$		6		20	
Turn-Off Delay Time	t _{d(off)}	$V_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{GEN}} = 6 \Omega$		29		ns	
Fall Time	t _f	$V_{\text{GEN}} = 10$ V, $V_{\text{GEN}} = 0.22$		8			
Input Capacitance	C _{iss}			1379			
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ Mhz}$		156		pF	
Reverse Transfer Capacitance	C _{rss}			115			

Notes

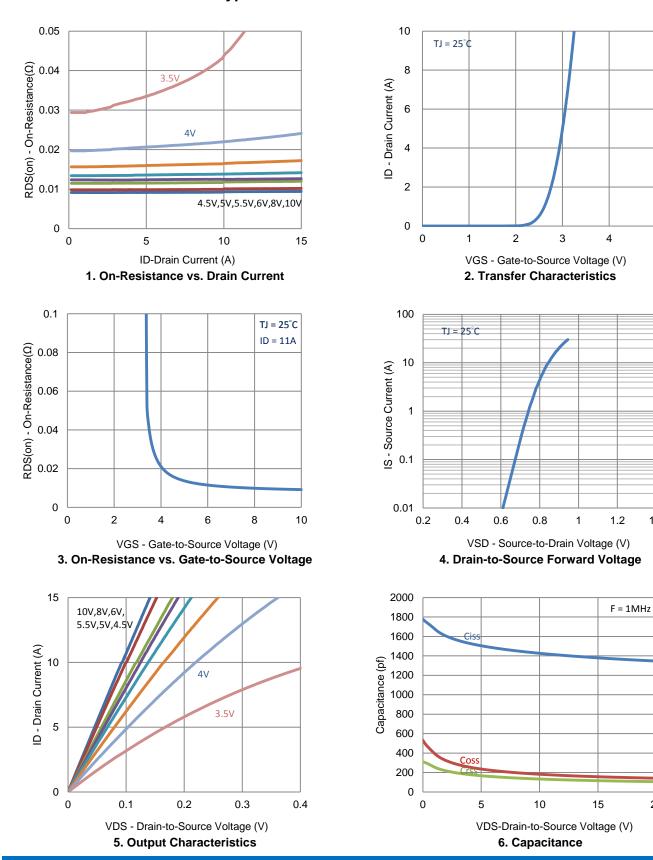
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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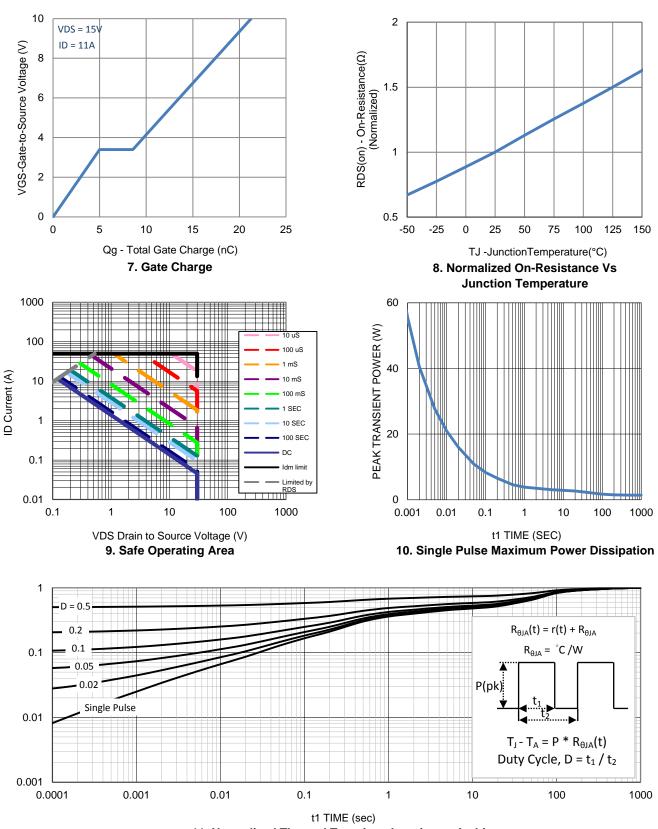
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Typical Electrical Characteristics



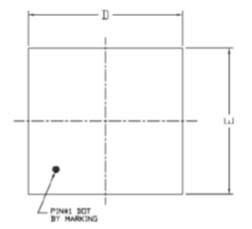
Typical Electrical Characteristics

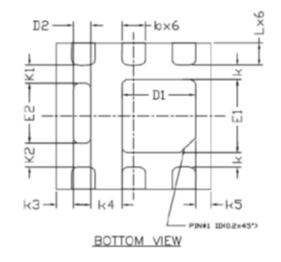
11. Normalized Thermal Transient Junction to Ambient

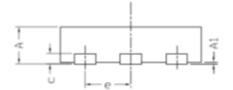
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4

Package Information







SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.50	0, 55	0.60	0.020	0.022	0.024
A1	0.00		0.05	0.000		0.002
b	0.25	0.30	0.35	0.010	0.012	0.014
с	0.152 REF				0.006 REF	
D	1.90	2.00	2.10	0.075	0.079	0.083
D1	0.85	0.95	1.05	0.033	0.037	0.041
D2	0.13	0.23	0.33	0.005	0.009	0.013
E	1.90	2.00	2.10	0.075	0.079	0.083
E1	0.90	1.00	1.10	0.035	0.039	0.043
E2	0.72	0.82	0.92	0.028	0.032	0.036
c	0.65 BSC			0.026 BSC		
K	0.20 BSC		0.008 BSC			
K1	0.25 BSC			0.010 BSC		
K2	0.33 BSC			0.013 BSC		
K3	0.22 BSC			0.009 BSC		
K4	0.40 BSC			0.016 BSC		
K5	0.20 BSC			0.008 BSC		
L	0.25	0.30	0.35	0.010	0.012	0.014